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	<b>Applicant</b> Nobuyasu KANEKAWA et al.	
	<b>Filing Date</b> August 31, 2001	<b>Group</b>

## U.S. PATENT DOCUMENTS

Examiner Initial		Document Number	Date	Name	Class	Sub-Class	Filing Date (if appropriate)
	AA						
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						

## FOREIGN PATENT DOCUMENTS

		Document	Date	Country	Class	Sub-class	Translation Yes   No
70	AK	11-136293	5/21/99	Japan			Abstract
75	AL	11-317445	11/16/99	Japan			Abstract
	AM						
	AN						
	AO						
	AP						

## OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

75	AQ	Article entitled "Application Technique of Power MOSFET" by Hiroshi Yamazaki, issued by Nikkan Industry Newspaper Co., pp. 55-57					
1	AR	1					
	AS						

EXAMINER	<i>[Signature]</i>	DATE CONSIDERED	4/24/04
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